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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/810,804	03/29/2004	Chang-Rong Wu	WUCH3037/EM	9777	
23364	7590 03/09/2006		EXAM	EXAMINER	
BACON & THOMAS, PLLC			TOLEDO, FERNANDO L		
625 SLATERS FOURTH FLO			ART UNIT	PAPER NUMBER	
ALEXANDRI	IA, VA 22314		2823		
•			DATE MAILED: 03/09/2000	6	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/810,804	WU ET AL.	
Office Action Summary	Examiner	Art Unit	
	Fernando Toledo	2823	
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet wi	th the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory perions for the provision of the provision of the period for reply will, by state and the period for reply will, by state and the period for reply will, by state and patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNIC 1.136(a). In no event, however, may a re- od will apply and will expire SIX (6) MON' tute, cause the application to become AB.	CATION. Poply be timely filed THS from the mailing date of this communication ANDONED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 13	December 2005.		
2a) ☐ This action is FINAL . 2b) ☑ The	his action is non-final.		
3) Since this application is in condition for allow	•	• •	s is
closed in accordance with the practice unde	r <i>Ex parte Quayle</i> , 1935 C.D	. 11, 453 O.G. 213.	
Disposition of Claims			
4) ⊠ Claim(s) <u>1-4</u> is/are pending in the application 4a) Of the above claim(s) is/are withden 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-4</u> is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and	rawn from consideration.		
Application Papers			
9) The specification is objected to by the Exami	ner.		
10) The drawing(s) filed on is/are: a) a	ccepted or b) objected to t	y the Examiner.	
Applicant may not request that any objection to the	ne drawing(s) be held in abeyan	ce. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the	•	,	• •
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a li	ents have been received. ents have been received in Apriority documents have been eau (PCT Rule 17.2(a)).	oplication No received in this National Stage	
Attachment(s)	_		
 Notice of References Cited (PTO-892) D Notice of Draftsperson's Patent Drawing Review (PTO-948) 		ummary (PTO-413))/Mail Date	
Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/C Paper No(s)/Mail Date		formal Patent Application (PTO-152)	

Application/Control Number: 10/810,804

Art Unit: 2823

DETAILED ACTION

Prior Art Rejections

Statutory Basis

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The Rejections

Claims 1 and 4 are rejected under 35 U.S.C. 103(a) as being unpatentable over Beintner et al.

Beintner discloses a structure similar to that claimed by the applicant. Element 200 corresponds to applicant's substrate. Upon the substrate 200 a pad oxide film 201 and a pad nitride layer 203 are provided. (See column 4, lines 1-20). A hard mask layer or layers is then optionally provided so as to more efficiently etch trenches 202b down deep into the substrate. The reference does teach that the hard mask layer or layers can be composed of BPSG, BSG, FSG, PSG, or the like and amorphous silicon layers.

However, Beintner does not teach the specific order of the layers and why one would use the BSG and BPSG out of the others. The only issue then is the structure of the mask layer. The applicant has not indicated any critically for the various materials and the order of the materials. The mere selection of which known masking materials

and their order on the basis of the suitability of the intended use does not rise to the level of significant patentable subject matter as such selection would have been obvious to one of ordinary skill through routine experimentation. See <u>In re Aller</u>, 105 USPQ 233 (CCPA 1955) and In re Leshin, 125 USPQ 416 (CCPA 1960).

Consequently, as the prior art discloses that the masks are well known to be composed of layers which can include BPSG and BSG, it would have been obvious to one of ordinary skill in the art to modify or clarify Beintner and have the first mask layer be BPSG and the second be BSG as applicant has not shown criticality of the order and these materials are well know layers to be used in masks.

Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over Beintner et al. as applied to claims 1 and 4 above, and further in view of Shimonishi et al.

Beintner teaches the features outlined above but lacks a discussion as to the annealing of the layers of the method prior to the trench making and after the application of BSG. Shimonishi teaches that baking of a mask containing the BSG, BPSG or PSG before etching or other processing prevents the mask from changing configuration upon etching. See column 8, lines 14-17 of Shimonishi. Therefore, it would have been obvious to one of ordinary skill in the art to us the teachings of Shimonishi to bake or anneal the mask of Beintner upon completion thereof and before the trench etching procedure.

Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Beintner as applied to claims 1 and 4 above, and further in view of applicant's admitted prior art.

Application/Control Number: 10/810,804

Art Unit: 2823

Beintner teaches the features outlined previously but lacks an explicit teaching of the manner of formation of the trenches using vapor of HF to etch in an anisotropic style.

Applicant's admitted prior art disclose that the hydrogen fluoride vapor can be effectively used to etch trenches wherein BSG is found in the mask structure.

Consequently, it would have been obvious to one of ordinary skill in the art to use the well know method of HF etching to etch the trenches of Beintner as this has been shown to be an effective manner of etching masks with BSG.

Response to Applicant's Arguments

The examiner has considered the applicant's comments and finds them persuasive. In light of a new reference, however, the examiner believes that the applicant's invention as recited in the claims is an obvious development from the prior art and generated the above non-final office action accordingly.

Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fernando Toledo whose telephone number is 571-272-1867. The examiner can normally be reached on Monday-Fridays 7-5:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S. Smith can be reached on 571-272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Art Unit: 2823

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Fernando Toledo Examiner Art Unit 2823

mss

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